

ALTERNISTORS

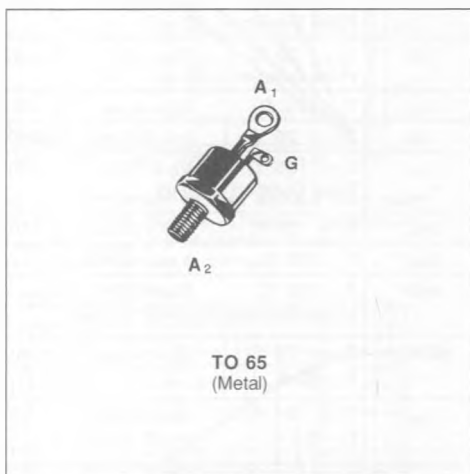
- $(di/dt)_c > 213 \text{ A/ms (400 Hz)}$

APPLICATIONS

- POWER CONTROL ON INDUCTIVE LOAD (motor, transformer...)
- HIGH FREQUENCY OR HIGH $(di/dt)_c$ LEVEL CIRCUITS.

DESCRIPTION

New range of solid state AC - switches with very high commutating capability.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state Current (360° conduction angle)	$T_C = 75^\circ\text{C}$	60	A
I_{TSM}	Non Repetitive Surge Peak on-state Current	$t = 10 \text{ ms}$	500	A
		$t = 8.3 \text{ ms}$	550	
		$t = 2.5 \text{ ms}$	840	
I^2t	I^2t Value for Fusing	$t = 10 \text{ ms}$	1250	A^2s
di/dt	Critical Rate of Rise of on-state Current (1)		100	$\text{A}/\mu\text{s}$
T_{stg} T_I	Storage and Operating Junction Temperature Range		- 40 to 150 - 40 to 125	$^\circ\text{C}$

Symbol	Parameter	TGDV							Unit
		601	602	604	606	608	610	612	
V_{DRM}	Repetitive Peak off-state Voltage (2)	100	200	400	600	800	1000	1200	V

(1) $I_G = 1.5 \text{ A}$ $di/dt = 1 \text{ A}/\mu\text{s}$

(2) $T_J = 125^\circ\text{C}$.

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(c-h)}$	Contact (case-heatsink) for Recommended Stud Torque	0.3	$^\circ\text{C}/\text{W}$
$R_{th(j-c)} \text{ DC}$	Junction to Case for DC	0.65	$^\circ\text{C}/\text{W}$
$R_{th(j-c)} \text{ AC}$	Junction to Case for 360° Conduction Angle ($F = 50 \text{ Hz}$)	0.48	$^\circ\text{C}/\text{W}$

GATE CHARACTERISTICS (maximum values)

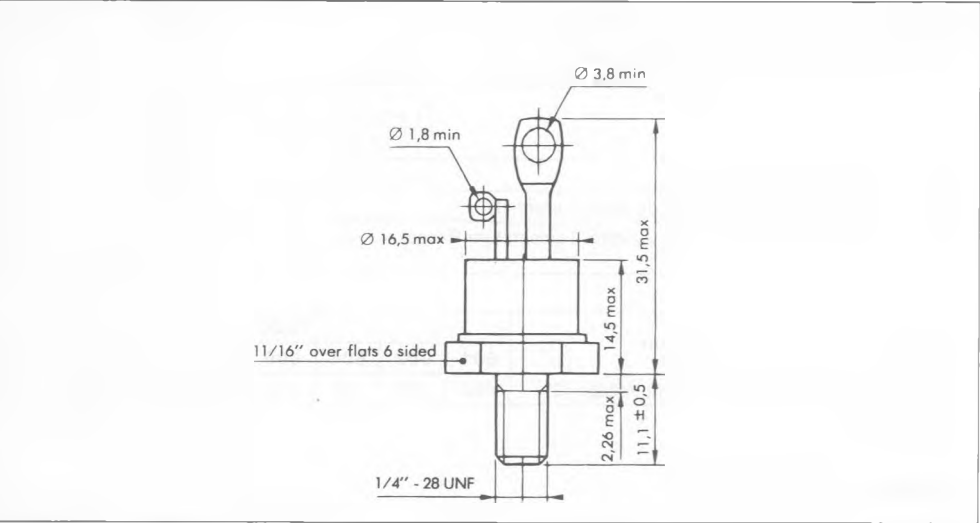
$P_{GM} = 40\text{ W}$ ($t_p = 10\text{ }\mu\text{s}$) $I_{GM} = 8\text{ A}$ ($t_p = 10\text{ }\mu\text{s}$)
 $P_G(AV) = 1\text{ W}$ $V_{GM} = 16\text{ V}$ ($t_p = 10\text{ }\mu\text{s}$)

ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions	Quadrants	Min.	Typ.	Max.	Unit
I_{GT}	$T_j = 25\text{ }^\circ\text{C}$ $V_D = 12\text{ V}$ $R_L = 33\text{ }\Omega$ Pulse Duration $> 20\text{ }\mu\text{s}$	I-II-III			200	mA
V_{GT}	$T_j = 25\text{ }^\circ\text{C}$ $V_D = 12\text{ V}$ $R_L = 33\text{ }\Omega$ Pulse Duration $> 20\text{ }\mu\text{s}$	I-II-III			1.5	V
V_{GD}	$T_j = 125\text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$	I-II-III	0.2			V
I_H^*	$T_j = 25\text{ }^\circ\text{C}$ $I_T = 500\text{ mA}$ Gate Open			50		mA
I_L	$T_j = 25\text{ }^\circ\text{C}$ $V_D = 12\text{ V}$ $I_G = 400\text{ mA}$ Pulse Duration $> 20\text{ }\mu\text{s}$	I-III		50		mA
		II		100		
V_{TM}^*	$T_j = 25\text{ }^\circ\text{C}$ $I_{TM} = 85\text{ A}$ $t_p = 10\text{ ms}$				2	V
I_{DRM}^*	$T_j = 100\text{ }^\circ\text{C}$ V_{DRM} Specified				5	mA
dv/dt^*	$T_j = 125\text{ }^\circ\text{C}$ Gate Open Linear Slope up to $V_D = 67\% V_{DRM}$	$V_{DRM} \leq 800\text{ V}$	500			V/ μs
		$V_{DRM} \geq 1000\text{ V}$	250			
$(di/dt)_c^*$	$T_C = 75\text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 85\text{ A}$	$(dv/dt)_c = 200\text{ V}/\mu\text{s}$	50			A/ms
		$(dv/dt)_c = 10\text{ V}/\mu\text{s}$	213			
t_{gt}	$T_j = 25\text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 85\text{ A}$ $I_G = 0.5\text{ A}$ $di_G/dt = 3.5\text{ A}/\mu\text{s}$	I-II-III		2.5		μs

* For either polarity of electrode A_2 voltage with reference to electrode A_1 .

PACKAGE MECHANICAL DATA : TO 65 Metal



Cooling method : by conduction (method C)
Marking : type number
Weight : 19 g
Polarity : Electrode A_2 to case
Stud torque : 3.5 mAN min - 3.8 mAN max

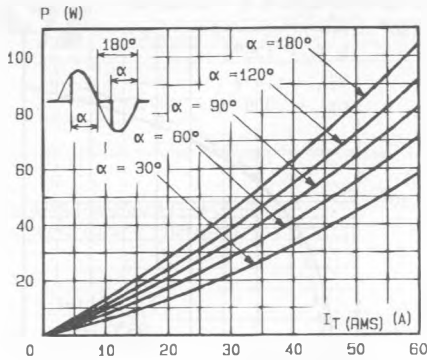


Fig.1 - Maximum mean power dissipation versus RMS on-state current.

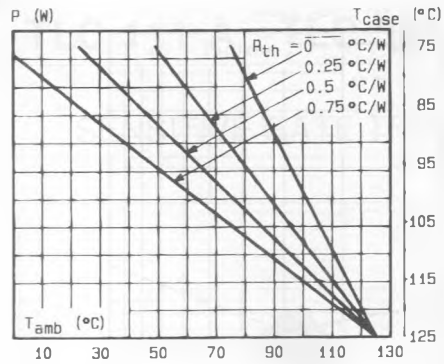


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact.

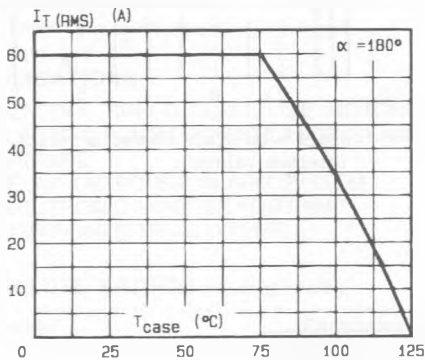


Fig.3 - RMS on-state current versus case temperature.

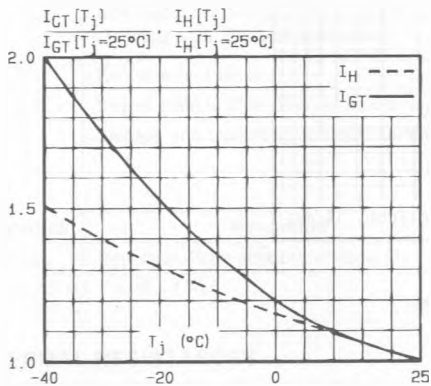


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

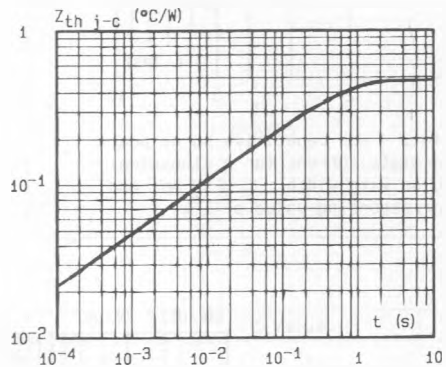


Fig.4 - Thermal transient impedance junction to case versus pulse duration.

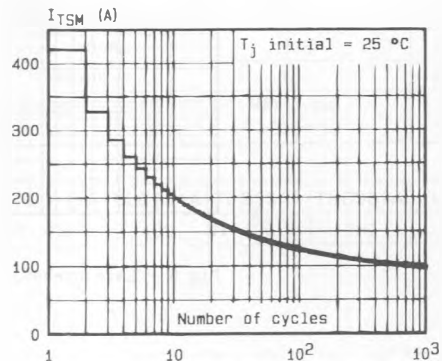


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

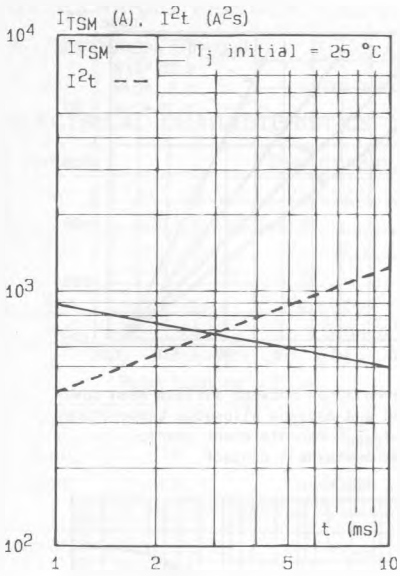


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10$ ms, and corresponding value of I^2t .

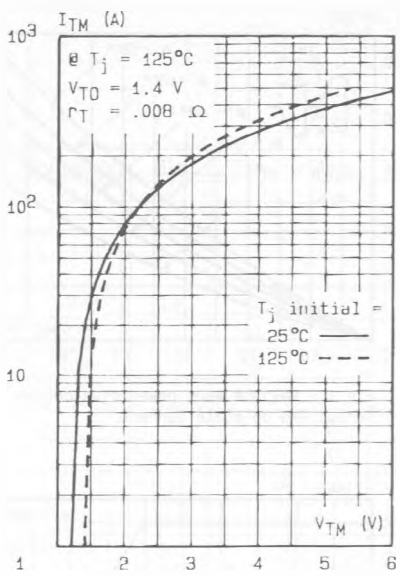


Fig.8 - On-state characteristics (maximum values) .

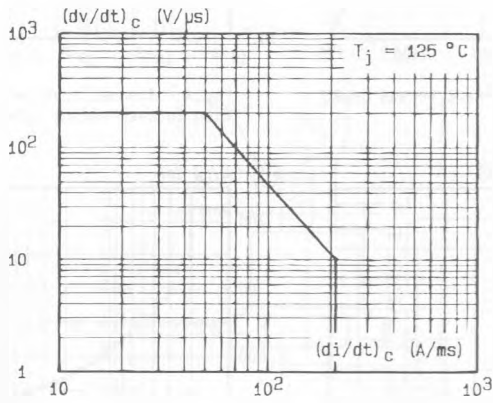


Fig.9 - Safe operating area.